NSN 5961-00-045-9050

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.520 inches

Overall Diameter:

1.250 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.190 inches

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

-80.0 breakdown voltage, collector-to-base, emitter open and -60.0 breakdown voltage, collector-to-emitter, base open and -60.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between -4.00 amperes source cutoff current and -15.00 amperes collector current, dc

Power Rating Per Characteristic:

20.0 watts collector power dissipation

Maximum Operating Tempurature Per Measurement Point:

95.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0